Vishay Semiconductors

High Speed Infrared Emitting Diodes, 850 nm, GaAlAs, DH



www.vishay.com

DESCRIPTION

VSMG28511 series are infrared, 850 nm emitting diodes in GaAlAs (DH) technology with high radiant power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

FEATURES

- Package type: surface mount
- Package form: GW, RGW
- Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.8
- Peak wavelength: $\lambda_p = 850 \text{ nm}$
- High reliability
- High radiant power
- High radiant intensity
- Angle of half intensity: $\varphi = \pm 12^{\circ}$
- · Low forward voltage
- Suitable for high pulse current operation
- Terminal configurations: Gullwing or reserve gullwing
- Package matches with detector VEMD2000X01 series
- Floor life: 4 weeks, MSL 2a, acc. J-STD-020
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Data transmission
- IR-illumination (CCTV)
- Miniature light barrier
- Photointerrupters
- Optical switch
- Shaft encoders
- IR emitter source for proximity applications
- Smoke detectors

PRODUCT SUMMARY					
COMPONENT	l _e (mW/sr)	φ (deg)	λ _p (nm)	t _r (ns)	
VSMG285011RG	40	± 12	850	20	
VSMG285011G	40	± 12	850	20	

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VSMG285011RG	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing		
VSMG285011G	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing		

Note

• MOQ: minimum order quantity





COMPLIANT

HALOGEN FREE <u>GREEN</u> (5-2008)



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ABSOLUTE MAXIMUM RATINGS (Tamb = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	5	V	
Forward current		I _F	100	mA	
Surge forward current	t _p = 100 μs	I _{FSM}	1	A	
Power dissipation		Pv	180	mW	
Junction temperature		Тj	100	°C	
Operating temperature range		T _{amb}	-40 to +85	°C	
Storage temperature range		T _{stg}	-40 to +100	°C	
Soldering temperature	Acc. figure 9, J-STD-020	T _{sd}	260	°C	
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	250	K/W	

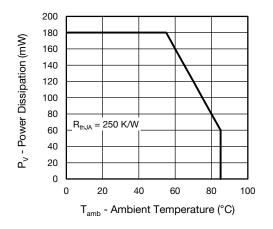
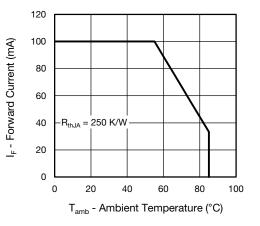


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature





PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 100 mA, t _p = 100 μs	V _F	1.25	1.5	1.8	V
	I _F = 1 A, t _p = 100 μs	V _F		2.9		V
Temperature coefficient of V _F	I _F = 1 mA	TK _{VF}		-1.8		mV/K
Reverse current	V _R = 5 V	I _R			10	μA
Junction capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0 mW/cm^{2}$	CJ		45		pF
Radiant intensity	I _F = 100 mA, t _p = 100 μs	l _e	20	40	60	mW/sr
	I _F = 1 A, t _p = 100 μs	l _e		320		mW/sr
Radiant power	I _F = 100 mA, t _p = 100 μs	фе		40		mW
Temperature coefficient of ϕ_{e}	I _F = 100 mA	TK¢e		-0.35		%/K
Angle of half intensity		φ		± 12		deg
Peak wavelength	I _F = 30 mA	λρ	830	850	870	nm
Spectral bandwidth	I _F = 30 mA	Δλ		35		nm
Temperature coefficient of λ_p	I _F = 30 mA	ΤΚλρ		0.25		nm/K
Rise time	I _F = 100 mA, 20 % to 80 %	tr		20		ns
Fall time	I _F = 100 mA, 20 % to 80 %	t _f		20		ns
Cut-off frequency	$I_{DC} = 70 \text{ mA}, I_{AC} = 30 \text{ mA pp}$	f _c		23		MHz



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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

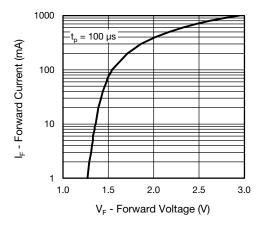


Fig. 3 - Forward Current vs. Forward Voltage

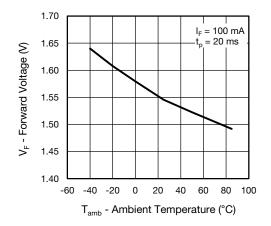


Fig. 4 - Forward Voltage vs. Ambient Temperature

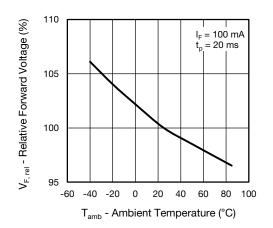


Fig. 5 - Relative Forward Voltage vs. Ambient Temperature

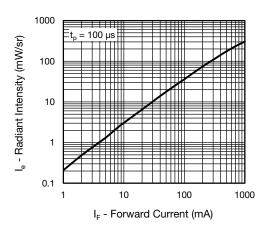


Fig. 6 - Radiant Intensity vs. Forward Current

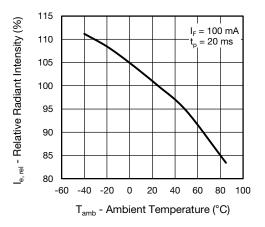


Fig. 7 - Relative Radiant Intensity vs. Ambient Temperature

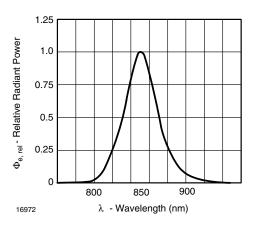


Fig. 8 - Relative Radiant Power vs. Wavelength

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0° 10° 20° 30° l_{e, rel} - Relative Radiant Intensity Angular Displacement 40° 1.0 0.9 50° 0.8 60° 70° 0.7 ÷ 80° 0.6 0.4 0.2 0 λ - Wavelength (nm)

Fig. 9 - Relative Radiant Intensity vs. Angular Displacement

SOLDER PROFILE

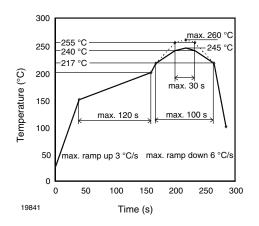


Fig. 10 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

VSMG285011RG, VSMG285011G

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DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

Conditions: $T_{amb} < 30\ ^\circ C,\ RH < 60\ \%$ Moisture sensitivity level 2a, acc. to J-STD-020.

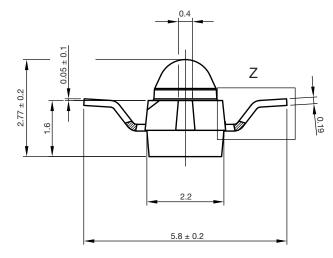
DRYING

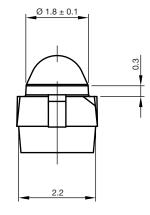
In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.



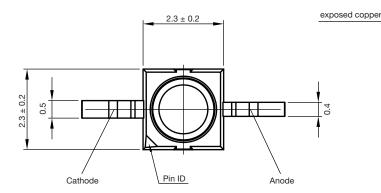
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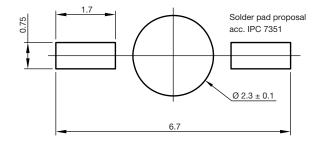
PACKAGE DIMENSIONS in millimeters: VSMG285011RG

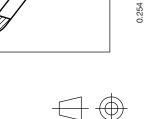








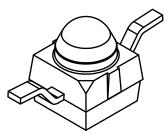




technical drawings according to DIN specifications

 1.1 ± 0.1

Not indicated tolerances ± 0.1



Drawing-No.: 6.544-5391.02-4 Issue: 2; 18.03.10 ²¹⁵¹⁷

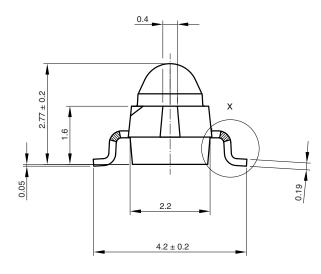
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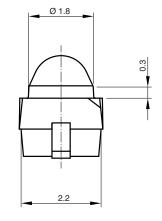
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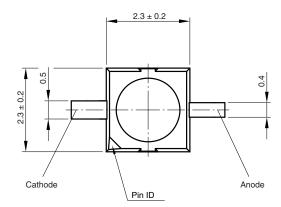


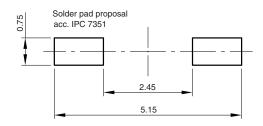
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PACKAGE DIMENSIONS in millimeters: VSMG285011G

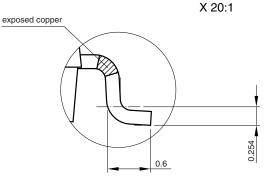






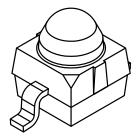


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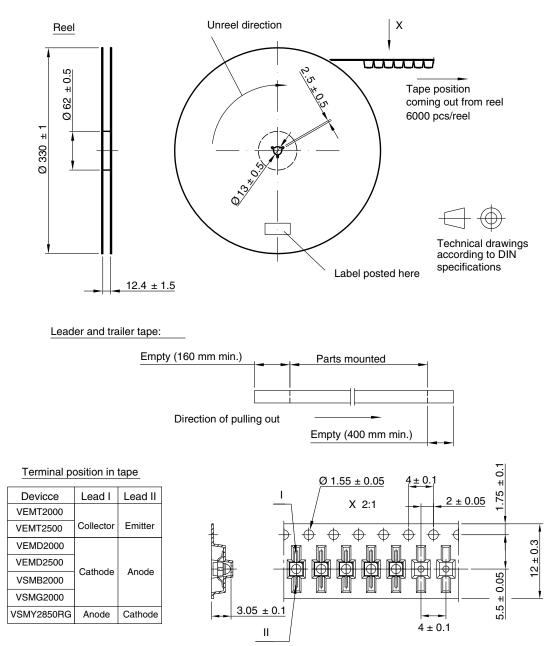
Not indicated tolerances ± 0.1





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TAPING AND REEL DIMENSIONS in millimeters: VSMG285011RG



Drawing-No.: 9.800-5100.01-4 Issue: 2; 18.03.10 ²¹⁵⁷²

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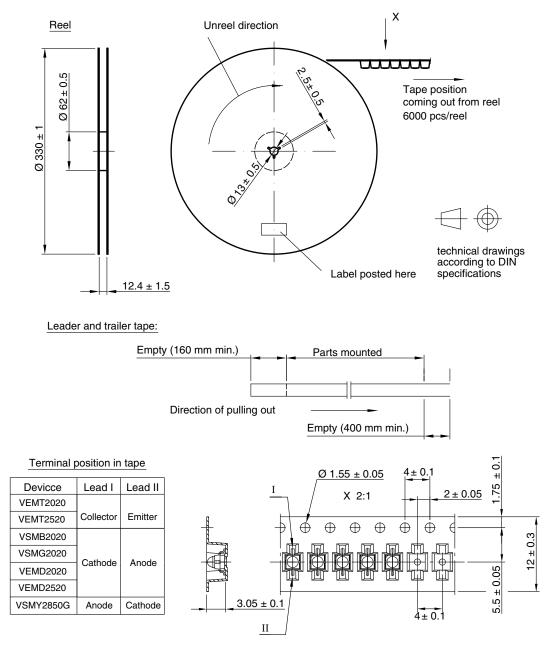
For technical questions, contact: emittertechsupport@vishay.com

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TAPING AND REEL DIMENSIONS in millimeters: VSMG285011G



Drawing-No.: 9.800-5091.01-4 Issue: 3; 18.03.10 21571



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